

## SPICE Model Parameters

Please copy this code from the SPICE model into LTSPICE (version 4) software for simulation of the GA01PNS80-CAL device.

```
*      MODEL OF GeneSiC Semiconductor Inc.
*
*      $Revision:   1.1           $
*      $Date:      30-APR-2015   $
*
*      GeneSiC Semiconductor Inc.
*      43670 Trade Center Place Ste. 155
*      Dulles, VA 20166
*
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*
*      These models are provided "AS IS, WHERE IS, AND WITH NO WARRANTY
*      OF ANY KIND EITHER EXPRESSED OR IMPLIED, INCLUDING BUT NOT LIMITED
*      TO ANY IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A
*      PARTICULAR PURPOSE."
*      Models accurate up to 2 times rated drain current.
*
*      Start of GA01PNS80-CAL SPICE Model
*
. MODEL GA01PNS80 D
+ IS      9.2491e-015
+ RS      1.02512
+ N       3.3373
+ IKF     0.00011784
+ EG      3.23
+ XTI     25
+ TRS1    -0.0024
+ CJO     2.7E-11
+ VJ      2.304
+ M       0.376
+ FC      0.5
+ BV      8000
+ IBV     1.00E-03
+ VPK     8000
+ IAVE    1
+ TYPE    SiC_PiN
+ MFG     GeneSiC_Semi
*
*      End of GA01PNS80-CAL SPICE Model
```